

Amendments to the Claims:

The following listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently Amended) An active matrix display device, comprising:
 - a first substrate;
 - a second substrate;
 - a third substrate;
 - active elements formed on the first substrate;
 - wiring lines formed on the second substrate;
 - electro-optical elements formed on the third substrate; and
 - an element chip having at least one active element configured to be peeled off from the first substrate and transferred onto at least one of the second substrate and the third substrate, the second substrate adhering configured to be adhered to the third substrate, the active elements being configured to be electrically connected to the wiring lines on one surface of the element chip facing the second substrate, and the active elements being configured to be electrically connected to the electro-optical elements on another surface of the element chip facing the third substrate.
2. (Original) The active matrix display device according to Claim 1,
the electrical connection being performed by a conductive material.
3. (Original) The active matrix display device according to Claim 2,
the conductive material being disposed in a position corresponding to the periphery of the element chip between the element chip and the second or third substrate, and the active elements being electrically connected to the electro-optical elements.
4. (Original) The active matrix display device according to Claim 2,

an opening being formed in the element chip, the conductive material being disposed in a position corresponding to the opening between the element chip and at least one of the second substrate and the third substrate, and the active elements being electrically connected to the electro-optical elements.

5. (Original) A thin film transistor display device, comprising:

the active matrix display device according to Claim 1, the active elements being thin film transistors.

6. (New) An active matrix display device comprising:

a first substrate including an organic light-emitting element, in which a light-emitting layer is formed between an anode and a cathode, and
a second substrate including a thin film transistor electrically connected to the organic light-emitting element, the first substrate being bonded to the second substrate, by using anisotropic conductive paste disposed in a position corresponding to the periphery of the thin film transistor,

the organic light-emitting element being located immediately above the thin film transistor.

7. (New) The active matrix display device according to claim 6, further comprising a wiring line on the second substrate, wherein the wiring line is connected to the thin film transistor by the anisotropic conductive paste disposed in a position corresponding to the periphery of the thin film transistor.